

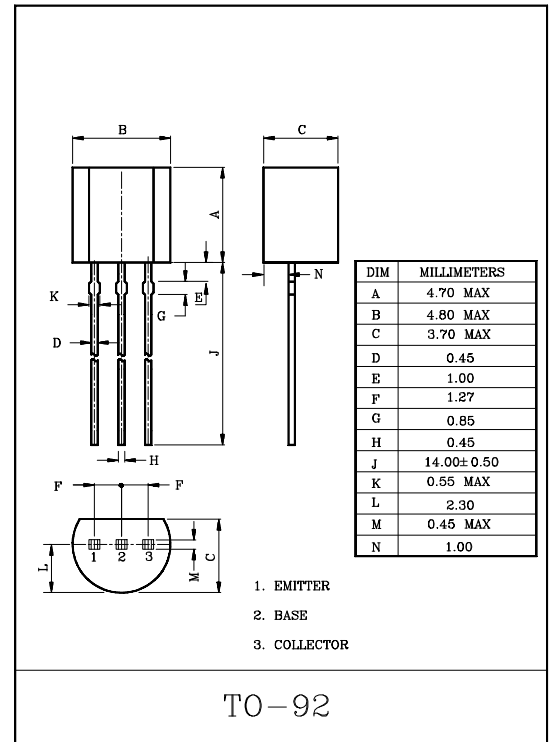
GENERAL PURPOSE APPLICATION.  
SWITCHING APPLICATION.

### FEATURES

- Excellent  $h_{FE}$  Linearity.  
:  $h_{FE}(I_C=0.1mA)/h_{FE}(I_C=2mA)=0.95(Typ.)$
- Low Noise :  $NF=1dB(Typ.)$ , at  $f=1kHz$
- Complementary to KTC945B.

### MAXIMUM RATINGS ( $T_a=25^\circ C$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	-50	V
Collector-Emitter Voltage	$V_{CEO}$	-50	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-150	mA
Collector Power Dissipation	$P_C$	625	mW
Junction Temperature	$T_j$	150	$^\circ C$
Storage Temperature Range	$T_{stg}$	-55~150	$^\circ C$



### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ C$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-100\mu A, I_E=0$	-60	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-1mA, I_B=0$	-50	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-100\mu A, I_C=0$	-5	-	-	V
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=-50V, I_E=0$	-	-	-0.1	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=-5V, I_C=0$	-	-	-0.1	$\mu A$
DC Current Gain	$h_{FE}$ (Note)	$V_{CE}=-6V, I_C=-2mA$	70	-	400	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-100mA, I_B=-10mA$	-	-0.1	-0.3	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-100mA, I_B=-10mA$	-	-	-1.1	V
Transition Frequency	$f_T$	$V_{CE}=-10V, I_C=-10mA$	-	300	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=-10V, I_E=0, f=1MHz$	-	4	7	pF
Noise Figure	NF	$V_{CE}=-6V, I_C=-0.1mA$ $R_g=10k\Omega, f=1kHz$	-	1.0	10	dB

Note :  $h_{FE}$  Classification O:70~140, Y:120~240, GR:200~400